

# High Speed, Precision JFET Input Operational Amplifier

## FEATURES

- **Guaranteed** Slew Rate: 23V/ $\mu$ s Min
- **Guaranteed** Offset Voltage: 250 $\mu$ V Max  
–55°C to 125°C: 750 $\mu$ V Max
- **Guaranteed** Drift: 5 $\mu$ V/°C Max
- **Guaranteed** Bias Current:  
70°C, 180pA Max  
125°C, 4nA Max
- Gain-Bandwidth Product: 8.5MHz Typ
- Settling Time to 0.05% (10V Step): 0.9 $\mu$ s Typ

## APPLICATIONS

- Fast D/A Output Amplifiers (12, 14, 16 Bits)
- High Speed Instrumentation
- Fast, Precision Sample and Hold
- Voltage-to-Frequency Converters
- Logarithmic Amplifiers

## DESCRIPTION

The LT<sup>®</sup>1022 JFET input operational amplifier combines high speed and precision performance.


A 26V/ $\mu$ s slew rate and 8.5MHz gain-bandwidth product are simultaneously achieved with offset voltage of typically 80 $\mu$ V, 1.5 $\mu$ V/°C drift, bias currents of 50pA at 70°C, 500pA at 125°C. The output delivers 20mA of load current without gain degradation.

The 250 $\mu$ V maximum offset voltage specification represents less than 1/2 least significant bit error in a 14-bit, 10V system.

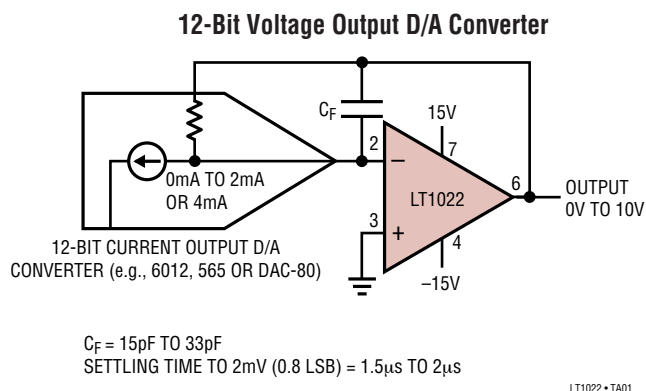
The LT1022A meets or exceeds all OP-16A and OP-16E specifications. It is faster and more accurate without stability problems at cold temperatures.

The LT1022 can be used as the output amplifier for 12-bit current output D/A converters, as shown below.

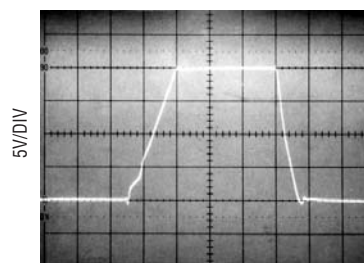
For a more accurate, lower power dissipation, but slower JFET input op amp, please refer to the LT1055 data sheet.

 LTC and LT are registered trademarks of Linear Technology Corporation.

## TYPICAL APPLICATION



## Large-Signal Response



A<sub>V</sub> = 1  
C<sub>L</sub> = 100pF  
T<sub>A</sub> = 25°C  
V<sub>S</sub> =  $\pm$ 15V

# LT1022

## ABSOLUTE MAXIMUM RATINGS

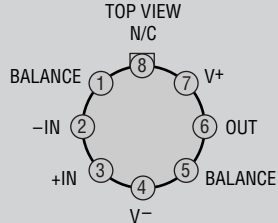
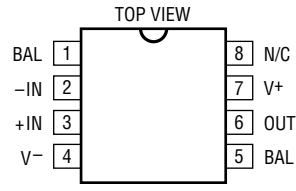
(Note 1)

Supply Voltage .....	±20V
Differential Input Voltage .....	±40V
Input Voltage .....	±20V
Output Short Circuit Duration .....	Indefinite

Operating Temperature Range

LT1022AM/1022M ( <b>OBSOLETE</b> ).....	-55°C to 125°C
LT1022AC/1022C .....	0°C to 70°C
Storage Temperature Range .....	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.).....	300°C

## PACKAGE/ORDER INFORMATION

 <p>METAL CAN H PACKAGE  <math>T_{JMAX} = 150^{\circ}\text{C}</math>, <math>\theta_{JA} = 150^{\circ}\text{C/W}</math>, <math>\theta_{JC} = 45^{\circ}\text{C/W}</math></p> <p><b>OBSOLETE PACKAGE</b>            Consider the N8 Package as an Alternate Source</p>	ORDER PART NUMBER	 <p>N8 PACKAGE 8-LEAD PDIP  <math>T_{JMAX} = 100^{\circ}\text{C}</math>, <math>\theta_{JA} = 130^{\circ}\text{C/W}</math></p>	ORDER PART NUMBER
	LT1022AMH LT1022MH LT1022ACH LT1022CH		LT1022CN8

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

$V_S = \pm 15\text{V}$ ,  $T_A = 25^{\circ}\text{C}$ ,  $V_{CM} = 0\text{V}$  unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1022AM LT1022AC			LT1022M, LT1022CH LT1022CN8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage (Note 2)	H Package N8 Package		80	250		100	600	$\mu\text{V}$ $\mu\text{V}$
$I_{OS}$	Input Offset Current	Fully Warmed Up		2	10		2	20	pA
$I_B$	Input Bias Current	Fully Warmed Up $V_{CM} = +10\text{V}$		±10 30	±50 100		±10 30	±50 150	pA pA
	Input Resistance—Differential —Common Mode	$V_{CM} = -11\text{V}$ to 8V $V_{CM} = 8\text{V}$ to 11V		$10^{12}$ $10^{12}$ $10^{11}$			$10^{12}$ $10^{12}$ $10^{11}$		$\Omega$ $\Omega$ $\Omega$
	Input Capacitance			4			4		pF
$e_n$	Input Noise Voltage	0.1Hz to 10Hz		2.5			2.8		$\mu\text{V}/\text{p-p}$
$e_n$	Input Noise Voltage Density	$f_0 = 10\text{Hz}$ (Note 3) $f_0 = 1\text{kHz}$ (Note 4)		28 14	50 20		30 15	60 22	nV/ $\sqrt{\text{Hz}}$ nV/ $\sqrt{\text{Hz}}$
$i_n$	Input Noise Current Density	$f_0 = 10\text{Hz}$ , 1kHz (Note 5)		1.8	4		1.8	4	fA/ $\sqrt{\text{Hz}}$
$A_{VOL}$	Large Signal Voltage Gain	$V_0 = \pm 10\text{V}$ $R_L = 2\text{k}$ $R_L = 1\text{k}$	150 130	400 300		120 100	400 300		V/mV V/mV
	Input Voltage Range		±10.5	±12		±10.5	±12		V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = \pm 10.5\text{V}$	86	94		82	92		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10\text{V}$ to ±18V	88	104		86	102		dB
$V_{OUT}$	Output Voltage Swing	$R_L = 2\text{k}$	±12	±13.2		±12	±13.2		V
SR	Slew Rate		23	26		18	24		V/ $\mu\text{s}$

1022fa

# ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$ ,  $T_A = 25^\circ C$ ,  $V_{CM} = 0V$  unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1022AM LT1022AC			LT1022M, LT1022CH LT1022CN8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
GBW	Gain-Bandwidth Product	f = 1MHz	8.5			8.0			MHz
$I_S$	Supply Current		5.2	7.0		5.2	7.0		mA
	Settling Time	A = +1 or A = -1 10V Step to 0.05% 10V Step to 0.02%	0.9 1.3			0.9 1.3			$\mu s$ $\mu s$
	Offset Voltage Adjustment Range	$R_{POT} = 100k$	$\pm 7$			$\pm 7$			mV

The ● denotes the specifications which apply over the full operating temperature range of  $V_{CM} = 0V$ ,  $0^\circ C \leq T_A \leq 70^\circ C$ .  $V_S = \pm 15V$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1022AC			LT1022CH LT1022CN8			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage (Note 2)	H Package	●	140	480	180	1000	$\mu V$	
		N8 Package	●			300	1700	$\mu V$	
	Average Temperature Coefficient of Input Offset Voltage	H Package N8 Package (Note 6)	●	1.3	5.0	1.8	9.0	$\mu V/^\circ C$ $\mu V/^\circ C$	
$I_{OS}$	Input Offset Current	Warmed Up, $T_A = 70^\circ C$	●	15	80	18	100	pA	
$I_B$	Input Bias Current	Warmed Up, $T_A = 70^\circ C$	●	$\pm 50$	$\pm 200$	$\pm 60$	$\pm 250$	pA	
$A_{VOL}$	Large-Signal Voltage Gain	$V_O = \pm 10V$ , $R_L = 2k$	●	80	250	60	250	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 10.4V$	●	85	93	80	91	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 18V$	●	86	103	84	101	dB	
$V_{OUT}$	Output Voltage Swing	$R_L = 2k$	●	$\pm 12$	$\pm 13.1$	$\pm 12$	$\pm 13.1$	V	

The ● denotes the specifications which apply over the full operating temperature range of  $-55^\circ C \leq T_A \leq 125^\circ C$ .  $V_S = \pm 15V$ ,  $V_{CM} = 0V$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	LT1022AM			LT1022M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage	(Note 2)	●	230	750	300	1500	$\mu V$	
		(Note 6)	●	1.5	5.0	2.0	9.0	$\mu V/^\circ C$	
$I_{OS}$	Input Offset Current	Warmed Up, $T_A = 125^\circ C$	●	0.3	2.0	0.30	3.0	nA	
$I_B$	Input Bias Current	Warmed Up, $T_A = 125^\circ C$	●	$\pm 0.5$	$\pm 4.0$	$\pm 0.7$	$\pm 6.0$	nA	
$A_{VOL}$	Large Signal Voltage Gain	$V_O = \pm 10V$ , $R_L = 2k$	●	40	120	35	120	V/mV	
CMRR	Common-Mode Rejection Ratio	$V_{CM} = \pm 10.4V$	●	85	92	80	90	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 17V$	●	86	102	84	100	dB	
$V_{OUT}$	Output Voltage Swing	$R_L = 2k$	●	$\pm 12$	$\pm 12.9$	$\pm 12$	$\pm 12.9$	V	

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** Offset voltage is measured under two different conditions:  
 (a) approximately 0.5 seconds after application of power;  
 (b) at  $T_A = 25^\circ C$ , with the chip self-heated to approximately  $45^\circ C$  to account for chip temperature rise when the device is fully warmed up.

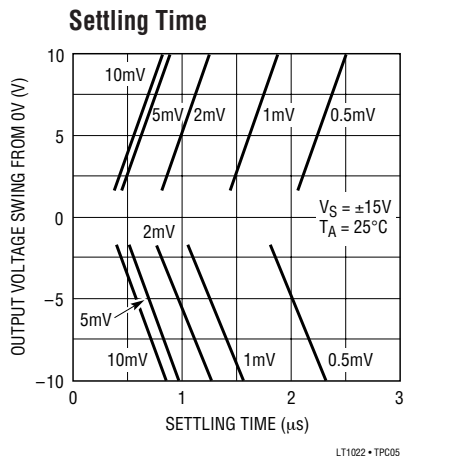
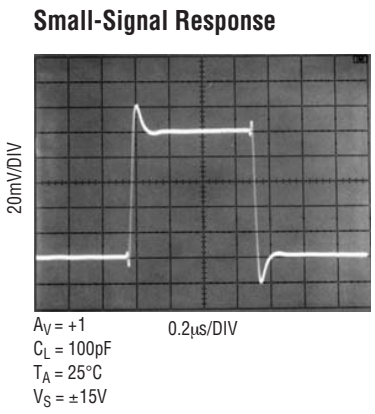
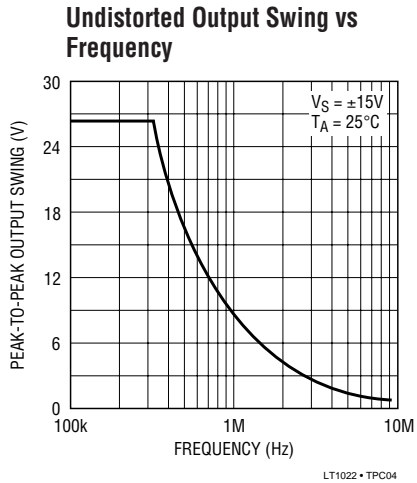
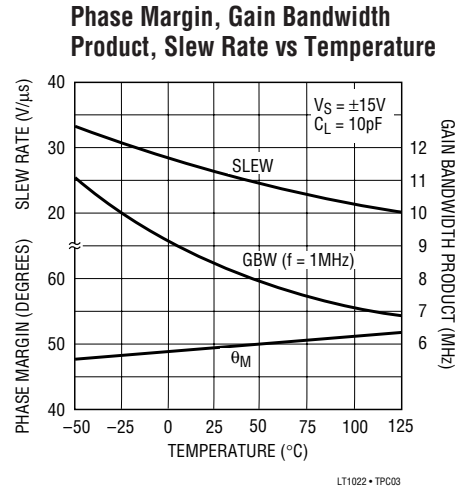
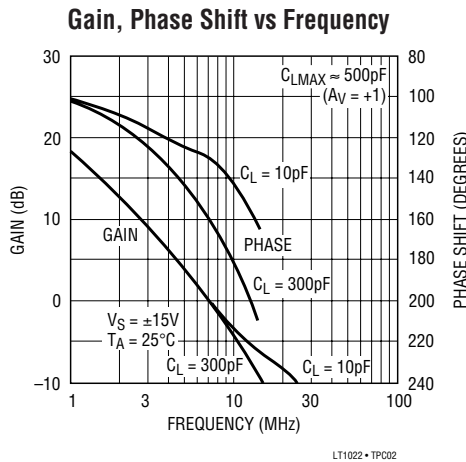
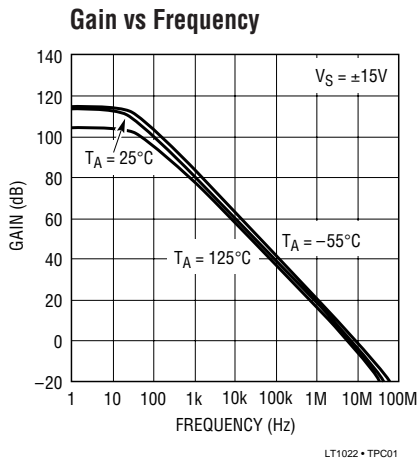
**Note 3:** 10Hz noise voltage density is sample tested on every lot of A grades. Devices 100% tested at 10Hz are available on request.

**Note 4:** This parameter is tested on a sample basis only.

**Note 5:** Current noise is calculated from the formula:  $i_n = (2qI_B)^{1/2}$ , where  $q = 1.6 \cdot 10^{-19}$  coulomb. The noise of source resistors up to  $1G\Omega$  swamps the contribution of current noise.

**Note 6:** Offset voltage drift with temperature is practically unchanged when the offset voltage is trimmed to zero with a 100k potentiometer between the balance terminals and the wiper tied to  $V^+$ . Devices tested to tighter drift specifications are available on request.

# TYPICAL PERFORMANCE CHARACTERISTICS



The typical behavior of many LT1022 parameters is identical to the LT1056. Please refer to the LT1055/1056 data sheet for the following typical performance characteristics:

- Input Bias and Offset Currents vs Temperature
- Input Bias Current Over the Common-Mode Range
- Distribution of Input Offset Voltage (H and N8 Package)
- Distribution of Offset Voltage Drift with Temperature
- Warm-Up Drift
- Long Term Drift of Representative Units
- 0.1Hz to 10Hz Noise
- Voltage Noise vs Frequency
- Noise vs Chip Temperature

- Short Circuit Current vs Time
- Output Impedance vs Frequency
- Common Mode Range vs Temperature
- Common Mode and Power Supply Rejections vs Temperature
- Common Mode Rejection Ratio vs Frequency
- Power Supply Rejection Ratio vs Frequency
- Voltage Gain vs Temperature
- Supply Current vs Supply Voltage
- Output Swing vs Load Resistance

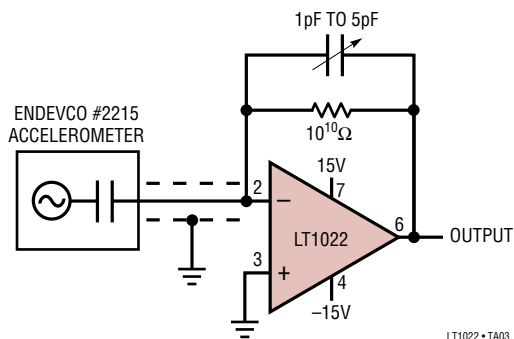
## APPLICATIONS INFORMATION

The LT1056 applications information is directly applicable to the LT1022. Please consult the LT1055/1056 data sheet for details on:

- (1) plug-in compatibility to industry standard devices
- (2) offset nulling
- (3) achieving picoampere/microvolt performance
- (4) phase-reversal protection
- (5) high speed operation (including settling time test circuit)
- (6) noise performance
- (7) simplified circuit schematic

## TYPICAL APPLICATIONS

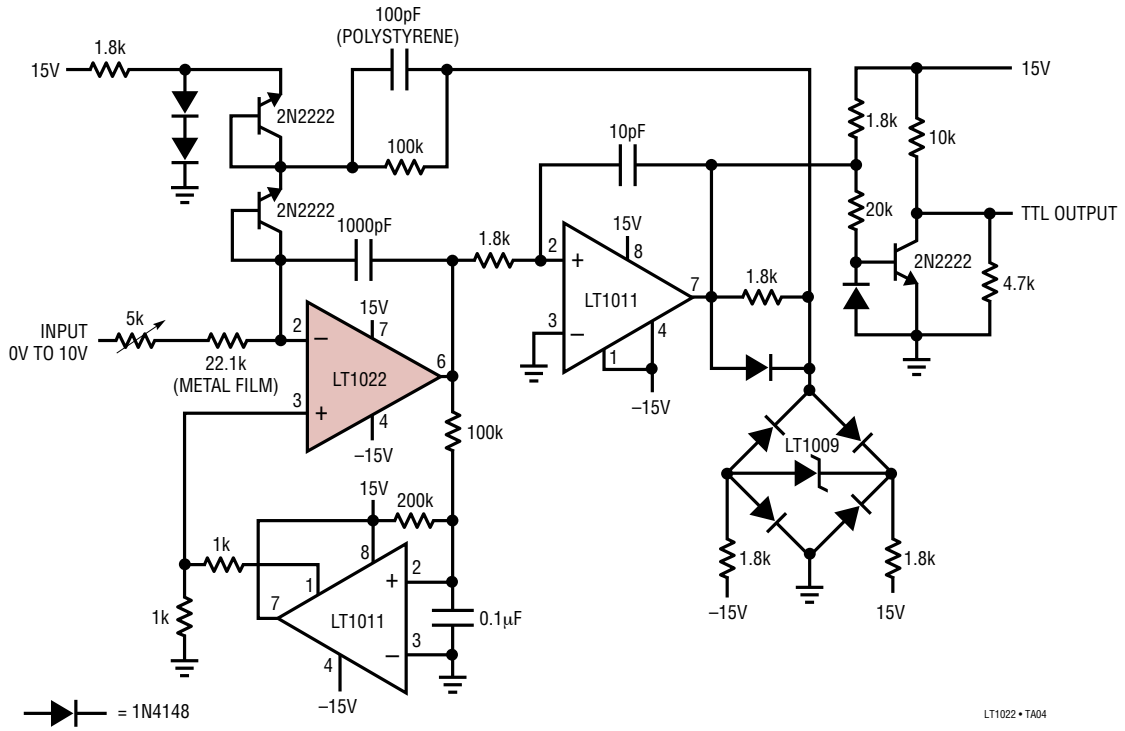
Fast Piezoelectric Accelerometer



LT1022 • TA03

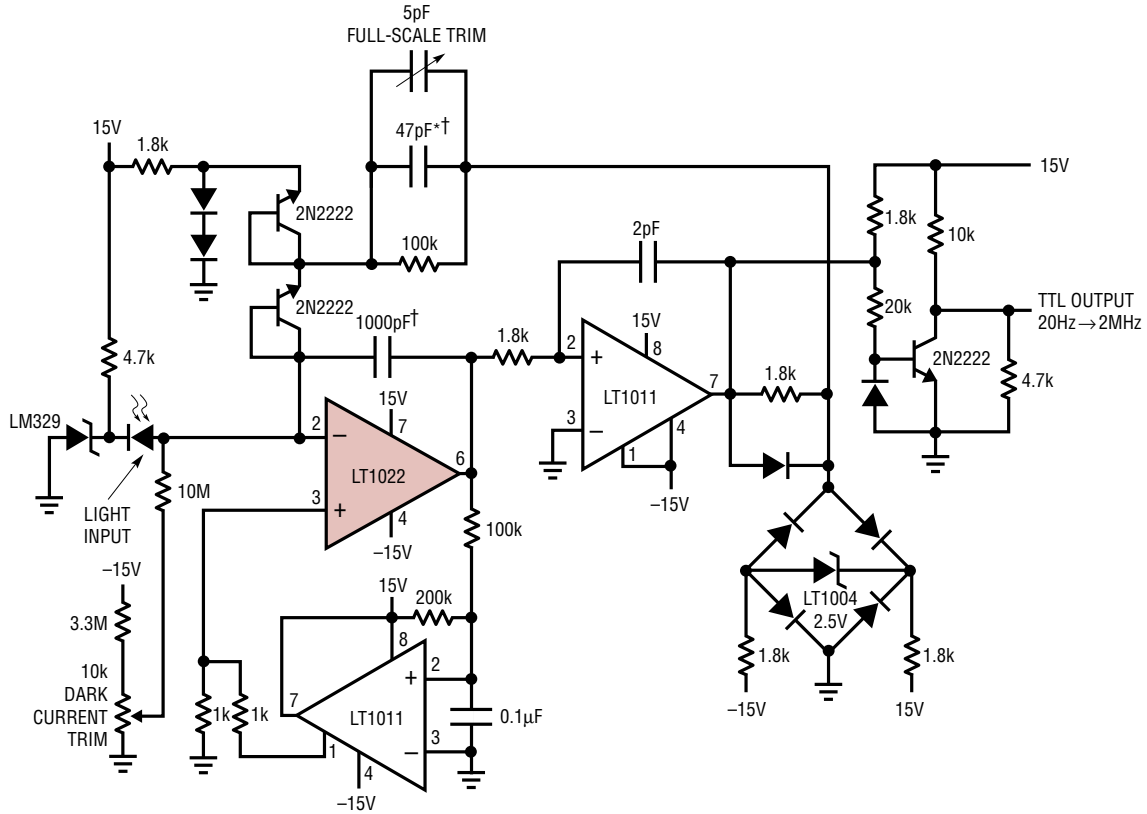
TYPICAL APPLICATIONS

10Hz to 1MHz Voltage-to-Frequency Converter



TYPICAL APPLICATIONS

PIN Photodiode-to-Frequency Converter



SCALE FACTOR =  
1nW/Hz AT 900 NANOMETERS FROM 20nW TO 2mW

= HEWLETT PACKARD PHOTODIODE HP5082-4204

= 1N4148

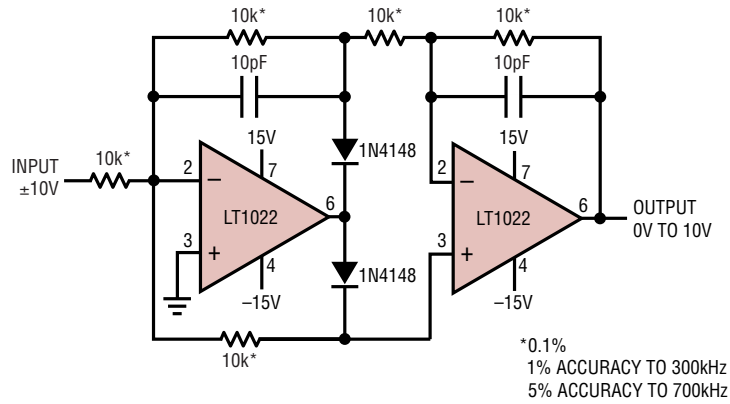
† POLYSTYRENE

\* SELECT VALUE FOR 2mW IN = 2MHz OUT

LT1022 • TA05

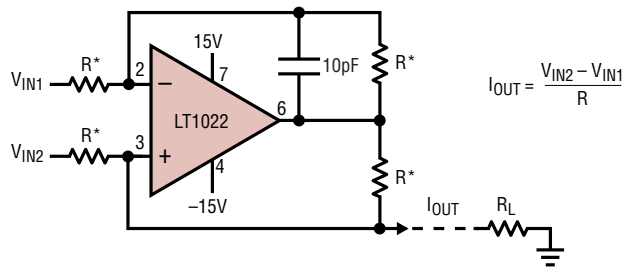
**TYPICAL APPLICATIONS**

**Wide Bandwidth Absolute Value Circuit**



LT1022 • TA06

**Fast, Differential Input Current Source**



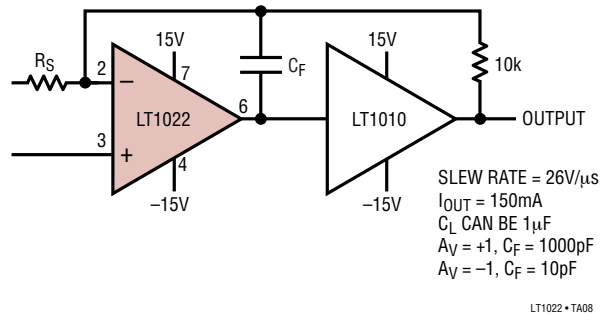
\*MATCH TO 0.01%  
FULL-SCALE POWER BANDWIDTH  
= 1MHz FOR  $I_{OUT}R = 8V_{P-P}$   
= 400kHz FOR  $I_{OUT}R = 20V_{P-P}$   
MAXIMUM  $I_{OUT} = 10mA_{P-P}$   
COMMON-MODE VOLTAGE AT LT1022 INPUT =  $\frac{I_{OUTP-P} \cdot R_L}{2}$

LT1022 • TA07

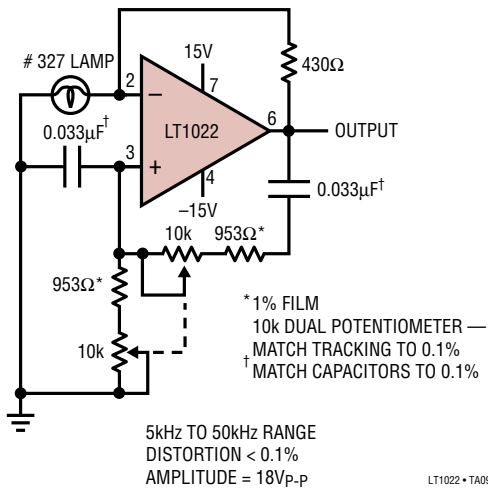


# TYPICAL APPLICATIONS

### High Output Current Op Amp

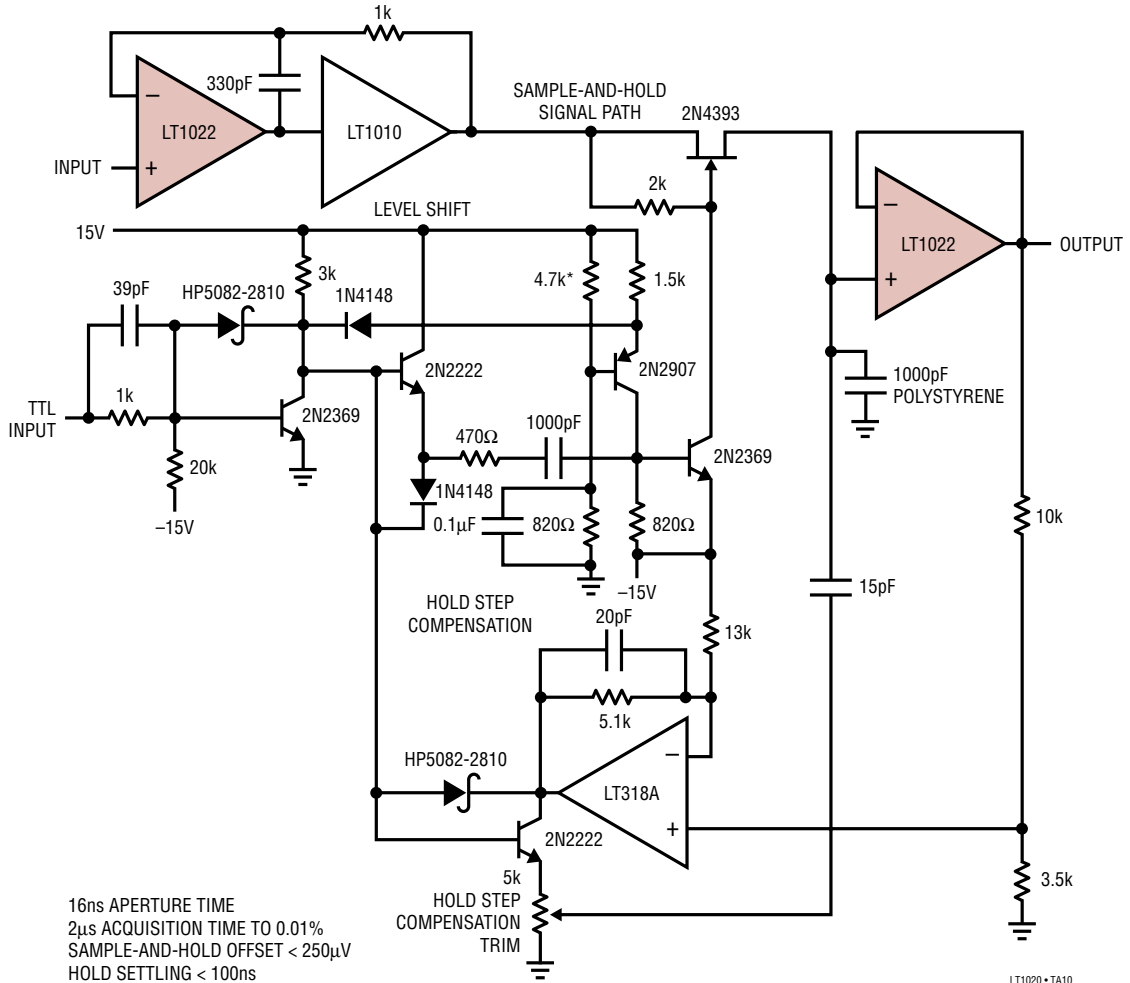


### Low Distortion Sine Wave Oscillator



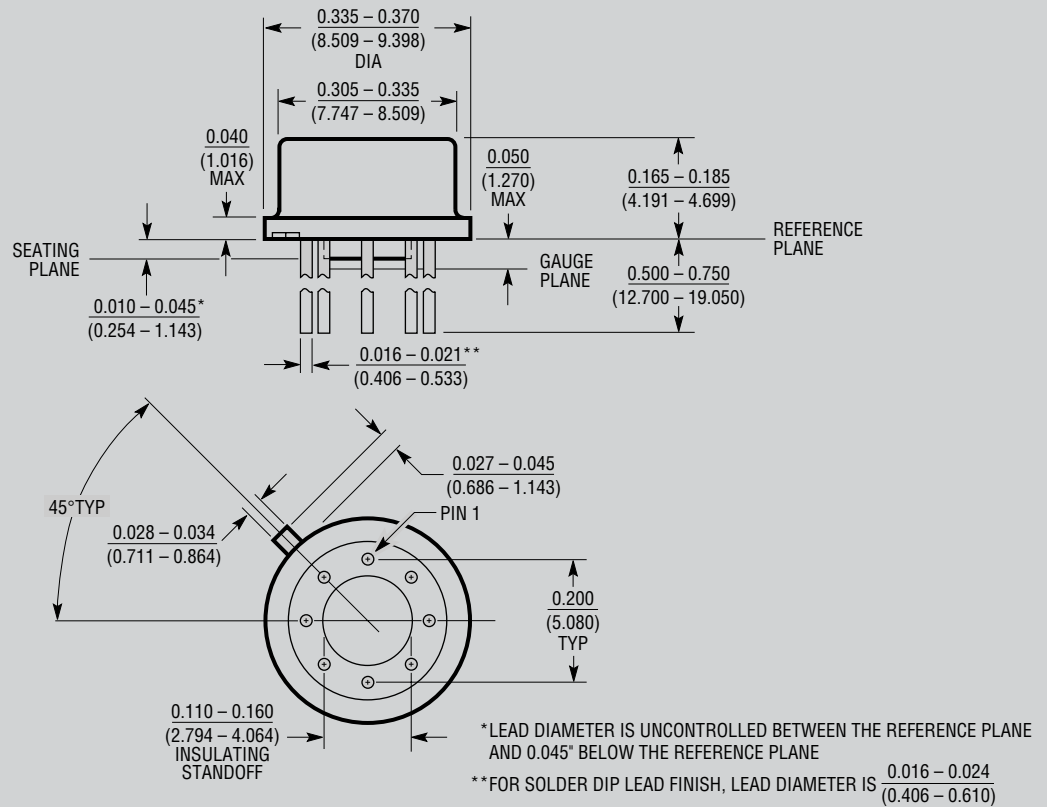
TYPICAL APPLICATIONS

Fast, Precision Sample-And-Hold



**PACKAGE DESCRIPTION**

**H Package**  
**8-Lead TO-5 Metal Can (.200 Inch PCD)**  
 (Reference LTC DWG # 05-08-1320)

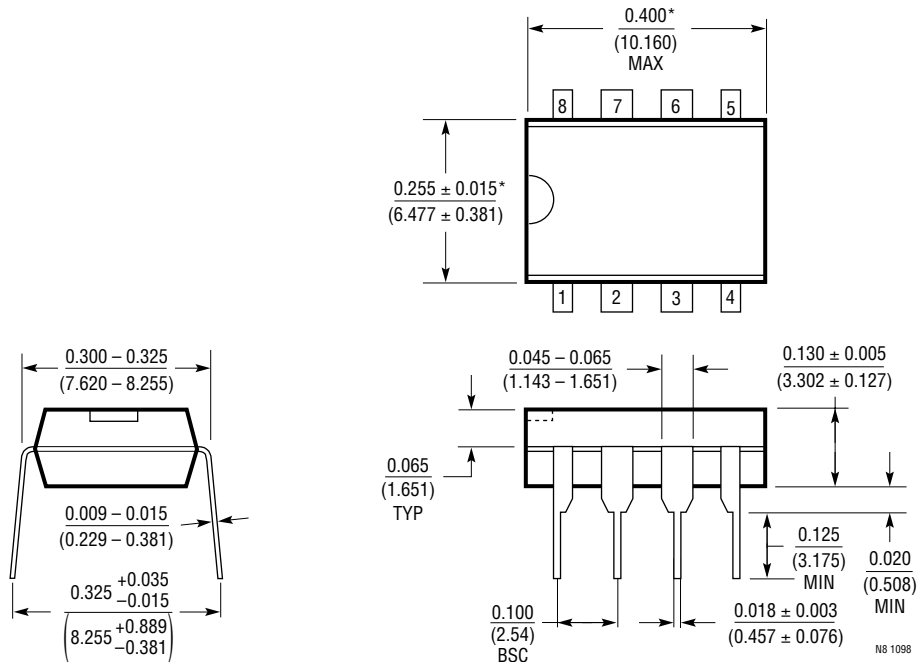


H8(TO-5) 0.200 PCD 1197

**OBSOLETE PACKAGE**

**PACKAGE DESCRIPTION**

**N8 Package**  
**8-Lead PDIP (Narrow .300 Inch)**  
 (Reference LTC DWG # 05-08-1510)



\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.  
 MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [High Speed Operational Amplifiers](#) category:*

*Click to view products by [Analog Devices](#) manufacturer:*

Other Similar products are found below :

[NJU7047RB1-TE2](#) [LTC6226IS8#PBF](#) [LTC6226HS8#PBF](#) [LT1058ACN](#) [LT1206CR](#) [LT1058ISW](#) [THS4222DGNR](#) [OPA2677IDDAR](#)  
[THS6042ID](#) [THS4221DBVR](#) [THS4081CD](#) [ADA4858-3ACPZ-R7](#) [LT6202IS5#TRMPBF](#) [LT1206CR#PBF](#) [LTC6253CMS8#PBF](#)  
[LT1813CDD#PBF](#) [ADA4851-4YRUZ-RL](#) [LT1037IN8#PBF](#) [LTC6401CUD-20#PBF](#) [LT1192CN8#PBF](#) [LTC6401IUD-26#PBF](#)  
[LT1037ACN8#PBF](#) [LTC6253CTS8#TRMPBF](#) [LT1399HVCS#PBF](#) [LT1993CUD-2#PBF](#) [LT1722CS8#PBF](#) [LT1208CN8#PBF](#)  
[LT1222CN8#PBF](#) [LT6203IDD#PBF](#) [LT6411IUD#PBF](#) [LTC6400CUD-26#PBF](#) [LTC6400CUD-8#PBF](#) [LT6211IDD#PBF](#) [OP27EN8#PBF](#)  
[LT1810IMS8#PBF](#) [OP37EN8#PBF](#) [LTC6253IMS8#PBF](#) [LT1360CS8](#) [OPA2132PAG4](#) [OPA2353UA/2K5](#) [OPA2691I-14D](#)  
[OPA4353UA/2K5](#) [OPA690IDRG4](#) [LMH6723MFX/NOPB](#) [ADP5302ACPZ-3-R7](#) [AD8007AKSZ-REEL7](#) [AD8008ARMZ](#) [AD8009JRTZ-](#)  
[REEL7](#) [AD8010ANZ](#) [AD8014ARTZ-REEL7](#)